**Product data sheet** 

# 1. General description

Ultrafast power diode in a SMB package.

### 2. Features and benefits

- · Fast switching
- SMB package
- High voltage capability
- Low forward voltage drop
- Low leakage current
- · Low thermal resistance
- · Soft recovery characteristic

## 3. Applications

- Discontinuous Current Mode (DCM) Power Factor Correction (PFC)
- use in switching power supplies, inverters and as free wheeling diodes
- · High frequency switched-mode power supplies

### 4. Quick reference data

#### Table 1. Quick reference data

| Symbol             | Parameter                           | Conditions                                                                             | Values | Unit |
|--------------------|-------------------------------------|----------------------------------------------------------------------------------------|--------|------|
| Absolute           | maximum rating                      |                                                                                        |        |      |
| $V_{RRM}$          | repetitive peak reverse voltage     |                                                                                        | 600    | V    |
| I <sub>F(AV)</sub> | average forward current             | $\delta$ = 0.5; square-wave pulse; $T_{lead} \le$ 158 °C;<br>Fig. 1; Fig. 2; Fig. 3    | 1      | Α    |
| I <sub>FRM</sub>   | repetitive peak forward current     | $\delta$ = 0.5 ; t <sub>p</sub> = 25 μs; T <sub>lead</sub> ≤ 158 °C; square-wave pulse | 2      | Α    |
| I <sub>FSM</sub>   | non-repetitive peak forward current | $t_p$ = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4                          | 35     | A    |
|                    |                                     | $t_p$ = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse                                 | 38     | А    |

Ultrafast power diode

# 5. Pinning information

### **Table 2. Pinning information**

| Pin | Symbol | Description | Simplified outline | Graphic symbol     |
|-----|--------|-------------|--------------------|--------------------|
| 1   | K      | cathode     |                    | v 14 A             |
| 2   | A      | anode       | 1 2                | K — A<br>001aaa020 |

# 6. Ordering information

#### **Table 3. Ordering information**

| Type number | Package<br>Name | Orderable part number | Packing method | Small packing quantity | Package version | Package issue date |
|-------------|-----------------|-----------------------|----------------|------------------------|-----------------|--------------------|
| MURS160B    | SMB             | MURS160BJ             | Reel           | 3000                   | SMBS            | 25-May-2017        |

# 7. Marking

#### Table 4. Marking codes

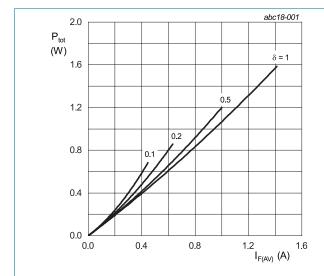
| Type number | Marking codes |
|-------------|---------------|
| MURS160B    | 160B          |

# 8. Limiting values

#### **Table 5. Limiting values**

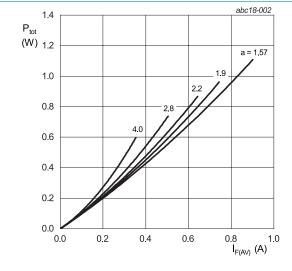
In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol             | Parameter                           | Conditions                                                                               | Values     | Unit |
|--------------------|-------------------------------------|------------------------------------------------------------------------------------------|------------|------|
| $V_{RRM}$          | repetitive peak reverse voltage     |                                                                                          | 600        | V    |
| $V_{\text{RWM}}$   | crest working reverse voltage       |                                                                                          | 600        | V    |
| $V_R$              | reverse voltage                     | DC                                                                                       | 600        | V    |
| I <sub>F(AV)</sub> | average forward current             | $\delta$ = 0.5; square-wave pulse; T <sub>lead</sub> ≤ 158 °C;<br>Fig. 1; Fig. 2; Fig. 3 | 1          | А    |
| I <sub>FRM</sub>   | repetitive peak forward current     | $\delta$ = 0.5 ; t <sub>p</sub> = 25 μs; T <sub>lead</sub> ≤ 158 °C; square-wave pulse   | 2          | Α    |
| I <sub>FSM</sub>   | non-repetitive peak forward current | $t_p$ = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse;<br>Fig. 4                         | 35         | Α    |
|                    |                                     | $t_p$ = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse                                   | 38         | Α    |
| T <sub>stg</sub>   | storage temperature                 |                                                                                          | -65 to 175 | °C   |
| T <sub>j</sub>     | junction temperature                |                                                                                          | 175        | °C   |



$$\begin{split} I_{F(AV)} &= I_{F(RMS)} \times \sqrt{\delta} \\ V_o &= 0.934 \text{ V; } R_s = 0.1331 \text{ } \Omega \end{split}$$

Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values

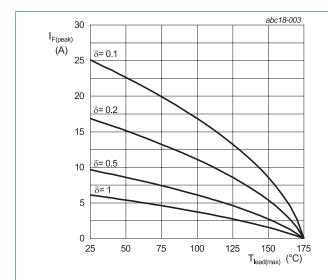


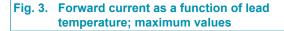
a = form factor =  $I_{F(RMS)}/I_{F(AV)}$   $V_o$  = 0.934 V;  $R_s$  = 0.1331  $\Omega$ 

Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

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**Ultrafast power diode** 





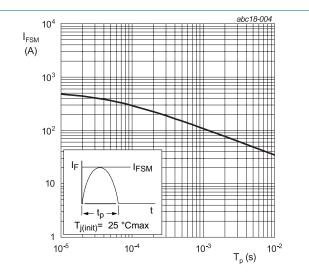


Fig. 4. Non-repetitive peak forward current as a function of pulse width; sinusoidal waveform; maximum values

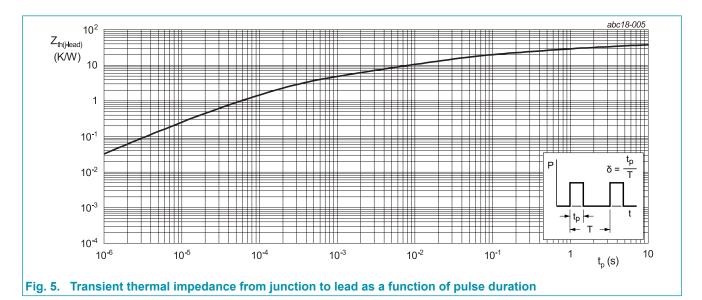
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## 9. Thermal characteristics

**Table 6. Thermal characteristics** 

| Symbol                  | Parameter                                                  | Conditions  | Min | Тур | Max | Unit |
|-------------------------|------------------------------------------------------------|-------------|-----|-----|-----|------|
| $R_{\text{th(j-lead)}}$ | thermal resistance from junction to lead                   | Fig. 5      | -   | -   | 14  | K/W  |
| $R_{\text{th(j-a)}}$    | thermal resistance<br>from junction to<br>ambient free air | in free air | -   | 115 | -   | K/W  |

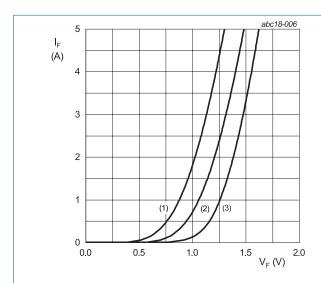


**Product data sheet** 

## 10. Characteristics

Table 7. Characteristics

| Symbol           | Parameter                     | Conditions                                                                                                                   | Min | Тур | Max  | Unit |
|------------------|-------------------------------|------------------------------------------------------------------------------------------------------------------------------|-----|-----|------|------|
| Static ch        | aracteristics                 |                                                                                                                              |     |     |      |      |
| $V_{F}$          | forward voltage               | I <sub>F</sub> = 1 A; T <sub>j</sub> = 25 °C                                                                                 | -   | -   | 1.25 | V    |
|                  |                               | I <sub>F</sub> = 1 A; T <sub>j</sub> = 150 °C                                                                                | -   | -   | 1.05 | V    |
| I <sub>R</sub>   | reverse current               | V <sub>R</sub> = 600 V; T <sub>j</sub> = 25 °C                                                                               | -   | -   | 5    | μA   |
|                  |                               | V <sub>R</sub> = 600 V; T <sub>j</sub> = 150 °C                                                                              | -   | -   | 150  | μA   |
| Dynamic          | characteristics               |                                                                                                                              |     |     |      |      |
| Q <sub>r</sub> r | reverse charge                | $I_F = 1 \text{ A}$ ; $V_R = 400 \text{ V}$ ; $dI_F/dt = 200 \text{ A/us}$ ; $T_J = 25 ^{\circ}\text{C}$ ; Fig. 7            | -   | 45  | -    | nC   |
|                  |                               | I <sub>F</sub> = 1 A; V <sub>R</sub> = 400 V; dI <sub>F</sub> /dt = 200 A/us;<br>T <sub>j</sub> = 125 °C; <u>Fig. 7</u>      | -   | 81  | -    | nC   |
| t,,              | reverse recovery time         | $I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 50 \text{ A/us};$<br>$T_j = 25 ^{\circ}\text{C}; Fig. 7$                   | -   | 40  | 75   | ns   |
|                  |                               | $I_F = 1 \text{ A}$ ; $V_R = 400 \text{ V}$ ; $dI_F/dt = 200 \text{ A/us}$ ; $T_j = 25 \text{ °C}$ ; Fig. 7                  | -   | 31  | -    | ns   |
|                  |                               | $I_F = 1 \text{ A}$ ; $V_R = 400 \text{ V}$ ; $dI_F/dt = 200 \text{ A/us}$ ; $T_j = 125 \text{ °C}$ ; Fig. 7                 | -   | 46  | -    | ns   |
|                  |                               | $I_F = 0.5 \text{ A}; I_R = 1 \text{ A}; I_{R(max)} = 0.25 \text{ A};$<br>$T_j = 25 ^{\circ}\text{C}; \text{ Step recovery}$ | -   | -   | 40   | ns   |
| I <sub>RM</sub>  | peak reverse recovery current | $I_F = 1 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 200 \text{ A/us};$<br>$T_j = 25 ^{\circ}\text{C}; Fig. 7$                 | -   | 2.9 | -    | А    |
|                  |                               | I <sub>F</sub> = 1 A; V <sub>R</sub> = 400 V; dI <sub>F</sub> /dt = 200 A/us;<br>T <sub>i</sub> = 125 °C; <u>Fig. 7</u>      | -   | 3.5 | -    | Α    |



 $\begin{array}{l} V_o=0.934~V;~R_s=0.1331~\Omega\\ (1)~T_j=150~^{\circ}C;~typical~values\\ (2)~T_j=150~^{\circ}C;~maximum~values\\ (3)~T_j=25~^{\circ}C;~maximum~values \end{array}$ 

Fig. 6. Forward current as a function of forward voltage

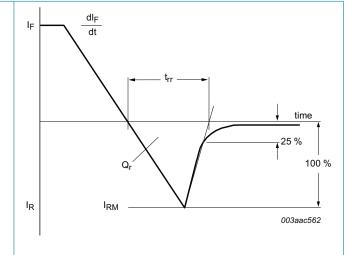
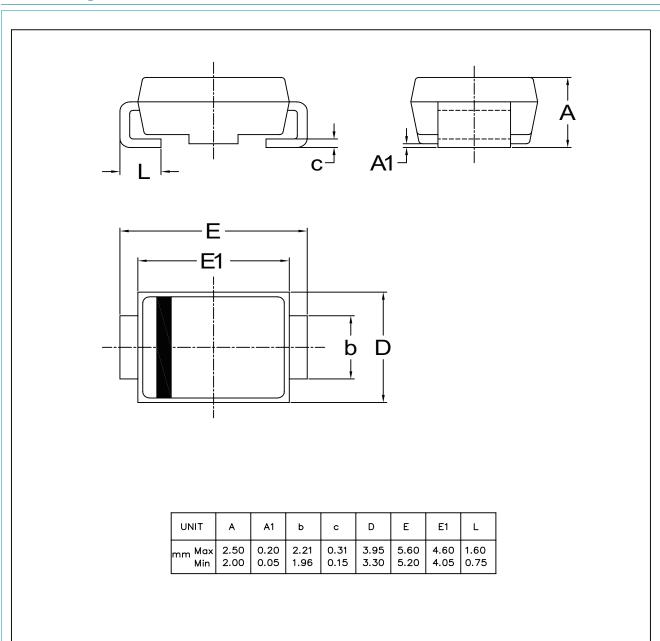


Fig. 7. Reverse recovery definitions; ramp recovery

# 11. Package outline



Remark: Dimensions D and E1 do not include mold flash.

#### Ultrafast power diode

## 12. Legal information

#### Data sheet status

| Document status [1][2]               | Product status [3] | Definition                                                                            |
|--------------------------------------|--------------------|---------------------------------------------------------------------------------------|
| Objective<br>[short] data<br>sheet   | Development        | This document contains data from the objective specification for product development. |
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# MURS160B

### Ultrafast power diode

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